

# Bongkwon Son

## List of Publications by Year in descending order

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Version: 2024-02-01

23  
papers

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citations

933447

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839539

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23  
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times ranked

211  
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#	ARTICLE	IF	CITATIONS
1	Direct Chemisorption-Assisted Nanotransfer Printing with Wafer-Scale Uniformity and Controllability. <i>ACS Nano</i> , 2022, 16, 378-385.	14.6	15
2	Grating and hole-array enhanced germanium lateral p-i-n photodetectors on an insulator platform. <i>Optics Express</i> , 2022, 30, 4706.	3.4	3
3	Metal-Semiconductor-Metal Photodetectors on a GeSn-on-Insulator Platform for 2 $\mu\text{m}$ Applications. <i>IEEE Photonics Journal</i> , 2022, 14, 1-6.	2.0	5
4	A heavily doped germanium pyramid array for tunable optical antireflection in the broadband mid-infrared range. <i>Journal of Materials Chemistry C</i> , 2022, 10, 5797-5804.	5.5	3
5	Direct bandgap GeSn nanowires enabled with ultrahigh tension from harnessing intrinsic compressive strain. <i>Applied Physics Letters</i> , 2022, 120, .	3.3	1
6	A highly ordered and damage-free Ge inverted pyramid array structure for broadband antireflection in the mid-infrared. <i>Journal of Materials Chemistry C</i> , 2021, 9, 9884-9891.	5.5	10
7	Low-power and high-detectivity Ge photodiodes by in-situ heavy As doping during Ge-on-Si seed layer growth. <i>Optics Express</i> , 2021, 29, 2940.	3.4	11
8	Surface plasmon enhanced GeSn photodetectors operating at 2 $\mu\text{m}$ . <i>Optics Express</i> , 2021, 29, 8498.	3.4	10
9	High Performance Flexible Visible-Blind Ultraviolet Photodetectors with Two-Dimensional Electron Gas Based on Unconventional Release Strategy. <i>ACS Nano</i> , 2021, 15, 8386-8396.	14.6	38
10	Sub-mA/cm <sup>2</sup> Dark Current Density, Buffer-Less Germanium (Ge) Photodiodes on a 200-mm Ge-on-Insulator Substrate. <i>IEEE Transactions on Electron Devices</i> , 2021, 68, 1730-1737.	3.0	10
11	Gourd-shaped hole array germanium (Ge)-on-insulator photodiodes with improved responsivity and specific detectivity at 1,550 $\mu\text{m}$ . <i>Optics Express</i> , 2021, 29, 16520.	3.4	7
12	Effects of high-temperature thermal annealing on GeSn thin-film material and photodetector operating at 2 $\mu\text{m}$ . <i>Journal of Alloys and Compounds</i> , 2021, 872, 159696.	5.5	4
13	Systematic study on photoexcited carrier dynamics related to defects in GeSn films with low Sn content at room temperature. <i>Semiconductor Science and Technology</i> , 2021, 36, 125018.	2.0	2
14	Metal-Semiconductor-Metal GeSn Photodetectors on Silicon for Short-Wave Infrared Applications. <i>Micromachines</i> , 2020, 11, 795.	2.9	24
15	Insights into the Origins of Guided Microtrenches and Microholes/rings from Sn Segregation in Germanium-Tin Epilayers. <i>Journal of Physical Chemistry C</i> , 2020, 124, 20035-20045.	3.1	9
16	Dark current analysis of germanium-on-insulator vertical p-i-n photodetectors with varying threading dislocation density. <i>Journal of Applied Physics</i> , 2020, 127, .	2.5	35
17	Growth and Characterizations of GeSn Films with High Sn Composition by Chemical Vapor Deposition (CVD) Using Ge <sub>2</sub> H <sub>6</sub> and SnCl <sub>4</sub> for Mid-IR Applications. <i>ECS Transactions</i> , 2020, 98, 91-98.	0.5	6
18	High-efficiency GeSn/Ge multiple-quantum-well photodetectors with photon-trapping microstructures operating at 2 $\mu\text{m}$ . <i>Optics Express</i> , 2020, 28, 10280.	3.4	67

#	ARTICLE	IF	CITATIONS
19	Resonant-cavity-enhanced responsivity in germanium-on-insulator photodetectors. Optics Express, 2020, 28, 23739.	3.4	22
20	High speed and ultra-low dark current Ge vertical p-i-n photodetectors on an oxygen-annealed Ge-on-insulator platform with GeO <sub>x</sub> surface passivation. Optics Express, 2020, 28, 23978.	3.4	23
21	Photo detection and modulation from 1,550 to 2,000 nm realized by a GeSn/Ge multiple-quantum-well photodiode on a 300-mm Si substrate. Optics Express, 2020, 28, 34772.	3.4	23
22	Dark Current Analysis of Vertical p-i-n Photodetectors on a Germanium-on-Insulator Platform. , 2019, , .		1
23	Metal-semiconductor-metal photodetectors on a GeSn-on-insulator platform. , 2019, , .		3